

SLOVENSKI STANDARD oSIST prEN IEC 60749-24:2025

01-februar-2025

Polprevodniški elementi - Metode za mehansko in klimatsko preskušanje - 24. del: Povečana odpornost na vlago

Semiconductor devices - Mechanical and climatic test methods - Part 24: Accelerated moisture resistance - Unbiased hast

Halbleiterbauelemente – Mechanische und klimatische Prüfverfahren - Teil 24: Beschleunigte Feuchtigkeitsbeständigkeit – Unvoreingenommene Hast

Dispositifs à semiconducteurs - Méthodes d'essais mécaniques et climatiques - Partie 24: Résistance à l'humidité accélérée - Hast sans polarisation

Document Preview

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ICS:

31.080.01 Polprevodniški elementi (naprave) na splošno Semiconductor devices in general

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47/2863/CDV

COMMITTEE DRAFT FOR VOTE (CDV)

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SUPERSEDES DOCUMENTS:		
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IEC TC 47 : SEMICONDUCTOR DEVICES		
SECRETARIAT:	SECRETARY:	
Korea, Republic of	Mr Cheolung Cha	
OF INTEREST TO THE FOLLOWING COMMITTEES:	HORIZONTAL FUNCTION(S):	
TC 91,TC 104		
ASPECTS CONCERNED:		
Environment,Safety		
SUBMITTED FOR CENELEC PARALLEL VOTING Teh Sta Not SUBMITTED FOR CENELEC PARALLEL VOTING		
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TITLE:

Semiconductor devices - Mechanical and climatic test methods - Part 24: Accelerated moisture resistance - Unbiased HAST

PROPOSED STABILITY DATE: 2030

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1 2		INTERNATIONAL ELECTROTECHNICAL COMMISSION
2		
4		SEMICONDUCTOR DEVICES –
5		MECHANICAL AND CLIMATIC TEST METHODS -
6		
7		Part 24: Accelerated moisture resistance – Unbiased HAST
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50 51	Th ed	nis edition includes the following significant technical changes with respect to the previous lition:
52	a)	rearrangement of clauses to reposition requirements;
53	b)	addition of 2 notes to the post-test electrical procedures.

47/2863/CDV

54 The text of this International Standard is based on the following documents:

Draft	Report on voting
47/XX/FDIS	47/XX/RVD

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56 Full information on the voting for its approval can be found in the report on voting indicated in 57 the above table.

58 The language used for the development of this International Standard is English.

59 This document was drafted in accordance with ISO/IEC Directives, Part 2, and developed in 60 accordance with ISO/IEC Directives, Part 1 and ISO/IEC Directives, IEC Supplement, 61 available at www.iec.ch/members_experts/refdocs. The main document types developed by 62 IEC are described in greater detail at www.iec.ch/publications.

A list of all parts of the IEC 60749 series, under the general title *Semiconductor devices* – *Mechanical and climatic test methods*, can be found in the IEC website.

The committee has decided that the contents of this document will remain unchanged until the stability date indicated on the IEC website under webstore.iec.ch in the data related to the specific document. At this date, the document will be

- 68 reconfirmed,
- 69 withdrawn,
- replaced by a revised edition, or **Standards.iteh.al**)
- amended.

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